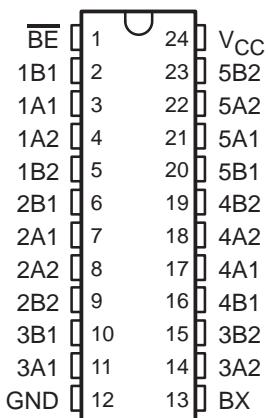


SN74CBT3383C  
10-BIT FET BUS-EXCHANGE SWITCH  
5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION  
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- **Undershoot Protection for Off-Isolation on A and B Ports Up to -2 V**
- **Bidirectional Data Flow, With Near-Zero Propagation Delay**
- **Low ON-State Resistance ( $r_{on}$ ) Characteristics ( $r_{on} = 3 \Omega$  Typical)**
- **Low Input/Output Capacitance Minimizes Loading and Signal Distortion ( $C_{io(OFF)} = 8 \text{ pF}$  Typical)**
- **Data and Control Inputs Provide Undershoot Clamp Diodes**
- **Low Power Consumption ( $I_{CC} = 3 \mu\text{A}$  Max)**
- **$V_{CC}$  Operating Range From 4 V to 5.5 V**
- **Data I/Os Support 0 to 5-V Signaling Levels (0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)**
- **Control Inputs Can be Driven by TTL or 5-V/3.3-V CMOS Outputs**
- **$I_{off}$  Supports Partial-Power-Down Mode Operation**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **ESD Performance Tested Per JESD 22**
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- **Supports Both Digital and Analog Applications: PCI Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating**

DB, DBQ, DGV, DW, OR PW PACKAGE  
(TOP VIEW)



#### description/ordering information

##### ORDERING INFORMATION

TA	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	SOIC – DW	Tube	SN74CBT3383CDW	CBT3383C
		Tape and reel	SN74CBT3383CDWR	
	SSOP – DB	Tape and reel	SN74CBT3383CDBR	CU383C
	SSOP (QSOP) – DBQ	Tape and reel	SN74CBT3383CDBQR	CBT3383C
	TSSOP – PW	Tube	SN74CBT3833CPW	CU383C
		Tape and reel	SN74CBT3833CPWR	
	TWSOP – DGV	Tape and reel	SN74CBT3833CDGVR	CU383C

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).



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**TEXAS  
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

**description/ordering information (continued)**

The SN74CBT3383C is a high-speed TTL-compatible FET bus-exchange switch with low ON-state resistance ( $r_{on}$ ), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT3383C provides protection for undershoot up to  $-2$  V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT3383C is organized as a 10-bit bus switch, or as a 5-bit bus-exchange switch with a single output-enable ( $\overline{BE}$ ) input that provides data exchanging between four signal ports. The select (BX) input controls the data path of the bus-exchange switch. When  $\overline{BE}$  is low, the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{BE}$  is high, a high-impedance state exists between the A and B ports.

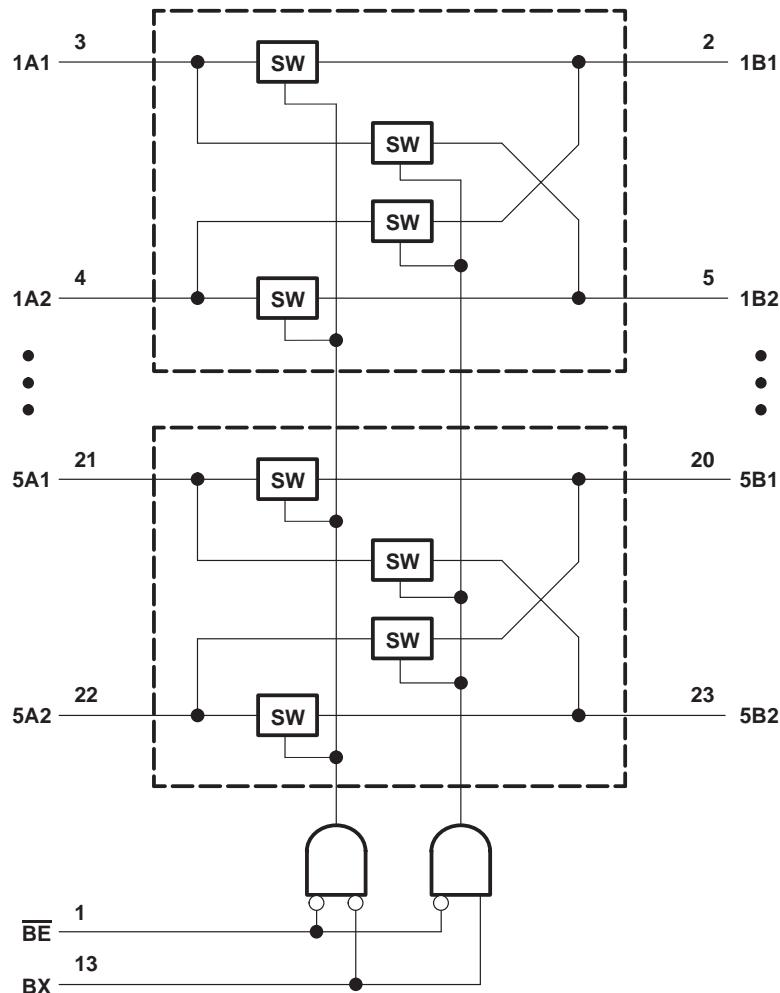
This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{BE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

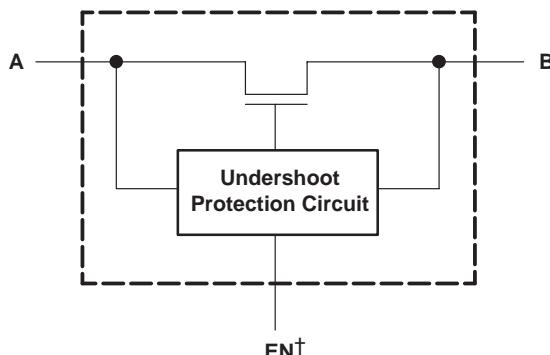
**FUNCTION TABLE**  
(each 5-bit bus-exchange)

INPUTS		INPUTS/OUTPUTS		FUNCTION
$\overline{BE}$	BX	1A1–5A1	1A2–5A2	
L	L	1B1–5B1	1B2–5B2	A1 port = B1 port, A2 port = B2 port
L	H	1B2–5B2	1B1–5B1	A1 port = B2 port, A2 port = B1 port
H	X	Z	Z	Disconnect

**logic diagram (positive logic)**



**simplified schematic, each FET switch (SW)**



† EN is the internal enable signal applied to the switch.

**SN74CBT3383C  
10-BIT FET BUS-EXCHANGE SWITCH  
5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION**

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**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†**

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to ground unless otherwise specified.

2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
3.  $V_I$  and  $V_O$  are used to denote specific conditions for  $V_{I/O}$ .
4.  $I_I$  and  $I_O$  are used to denote specific conditions for  $I_{I/O}$ .
5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 6)

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	4	5.5	V
$V_{IH}$	High-level control input voltage	2	5.5	V
$V_{IL}$	Low-level control input voltage	0	0.8	V
$V_{I/O}$	Data input/output voltage	0	5.5	V
$T_A$	Operating free-air temperature	-40	85	°C

NOTE 6: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER		TEST CONDITIONS			MIN	TYP†	MAX	UNIT
V <sub>IK</sub>	Control inputs	V <sub>CC</sub> = 4.5 V, I <sub>IN</sub> = -18 mA					-1.8	V
V <sub>IKU</sub>	Data inputs	V <sub>CC</sub> = 5 V, 0 mA > I <sub>I</sub> ≥ -50 mA, V <sub>IN</sub> = V <sub>CC</sub> or GND, Switch OFF					-2	V
I <sub>IN</sub>	Control inputs	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = V <sub>CC</sub> or GND					±1	µA
I <sub>OZ</sub> ‡		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 0 to 5.5 V, V <sub>I</sub> = 0, V <sub>IN</sub> = V <sub>CC</sub> or GND					±10	µA
I <sub>off</sub>		V <sub>CC</sub> = 0, V <sub>O</sub> = 0 to 5.5 V, V <sub>I</sub> = 0					10	µA
I <sub>CC</sub>		V <sub>CC</sub> = 5.5 V, I <sub>I/O</sub> = 0, V <sub>IN</sub> = V <sub>CC</sub> or GND, Switch ON or OFF					3	µA
ΔI <sub>CC</sub> §	Control inputs	V <sub>CC</sub> = 5.5 V, One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND					2.5	mA
C <sub>in</sub>	Control inputs	V <sub>IN</sub> = 3 V or 0					3.5	pF
C <sub>io(OFF)</sub>		V <sub>I/O</sub> = 3 V or 0, Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND					8	pF
C <sub>io(ON)</sub>		V <sub>I/O</sub> = 3 V or 0, Switch ON, V <sub>IN</sub> = V <sub>CC</sub> or GND					18.5	pF
r <sub>on</sub> ¶	V <sub>CC</sub> = 4 V, TYP at V <sub>CC</sub> = 4 V		V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA		8	12	Ω
	V <sub>CC</sub> = 4.5 V		V <sub>I</sub> = 0	I <sub>O</sub> = 64 mA		3	6	
				I <sub>O</sub> = 30 mA		3	6	
			V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA		5	10	

V<sub>IN</sub> and I<sub>IN</sub> refer to control inputs. V<sub>I</sub>, V<sub>O</sub>, I<sub>I</sub>, and I<sub>O</sub> refer to data pins.

† All typical values are at V<sub>CC</sub> = 5 V (unless otherwise noted), T<sub>A</sub> = 25°C.

‡ For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

§ This is the increase in supply current for each input that is at the specified voltage level, rather than V<sub>CC</sub> or GND.

¶ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 4 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	
t <sub>pd</sub> ‡	A or B	B or A		0.24		0.15	ns
t <sub>pd(s)</sub>	BX	A or B		5.8	1	5.3	ns
t <sub>en</sub>	BE	A or B		6.3	1	5.8	ns
t <sub>dis</sub>	BE	A or B		6	1	6	ns

# The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

# SN74CBT3383C

## 10-BIT FET BUS-EXCHANGE SWITCH

### 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

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#### undershoot characteristics (see Figures 1 and 2)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
$V_{OUTU}$	$V_{CC} = 5.5$ V, Switch OFF, $V_{IN} = V_{CC}$ or GND	2	$V_{OH} - 0.3$		V

† All typical values are at  $V_{CC} = 5$  V (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

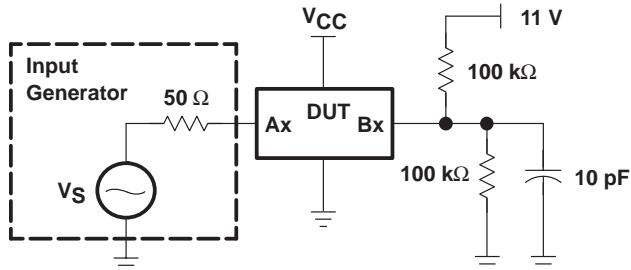


Figure 1. Device Test Setup

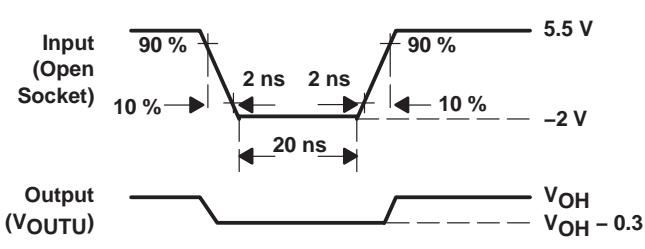
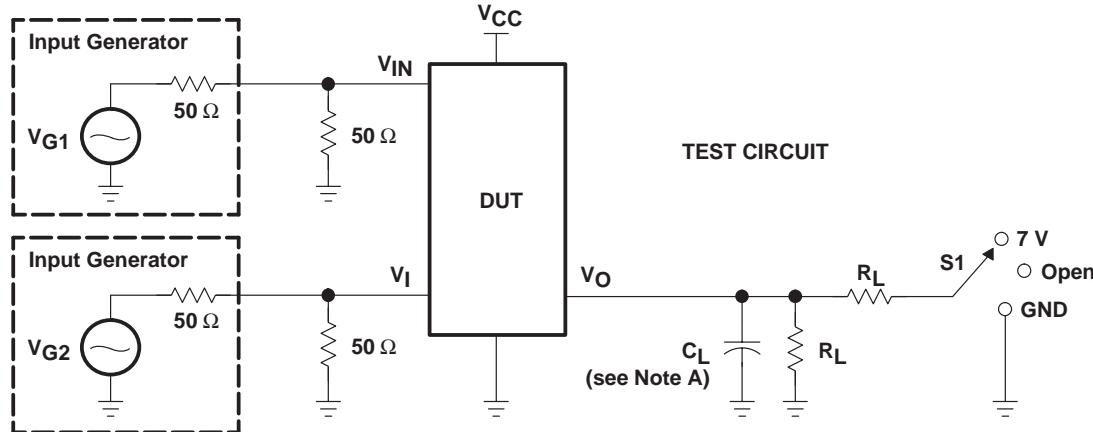
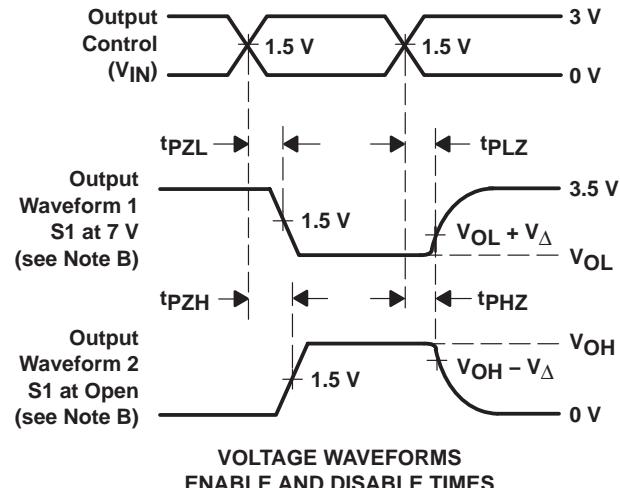
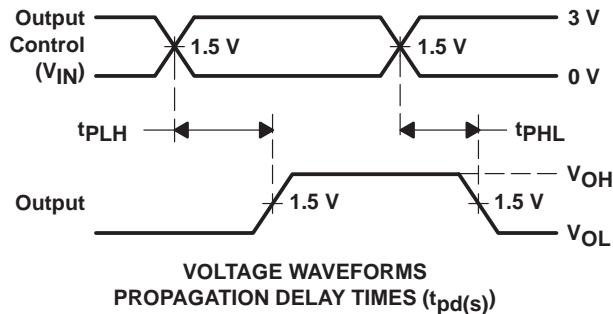


Figure 2. Transient Input Voltage ( $V_I$ ) and Output Voltage ( $V_{OUTU}$ ) Waveforms (Switch OFF)

**PARAMETER MEASUREMENT INFORMATION**



TEST	V <sub>CC</sub>	S1	R <sub>L</sub>	V <sub>I</sub>	C <sub>L</sub>	V <sub>Δ</sub>
t <sub>pd(s)</sub>	5 V ± 0.5 V 4 V	Open Open	500 Ω 500 Ω	V <sub>CC</sub> or GND V <sub>CC</sub> or GND	50 pF 50 pF	
t <sub>PLZ/tPZL</sub>	5 V ± 0.5 V 4 V	7 V 7 V	500 Ω 500 Ω	GND GND	50 pF 50 pF	0.3 V 0.3 V
t <sub>PHZ/tPZH</sub>	5 V ± 0.5 V 4 V	Open Open	500 Ω 500 Ω	V <sub>CC</sub> V <sub>CC</sub>	50 pF 50 pF	0.3 V 0.3 V



NOTES:

- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> ≤ 2.5 ns, t<sub>f</sub> ≤ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd(s)</sub>. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

**Figure 3. Test Circuit and Voltage Waveforms**

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74CBT3383CDBQR	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
SN74CBT3383CDBQRE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
SN74CBT3383CDBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CDBRE4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CDGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CDGVRE4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CDW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CDWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CDWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CDWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CPW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CPWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CPWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3383CPWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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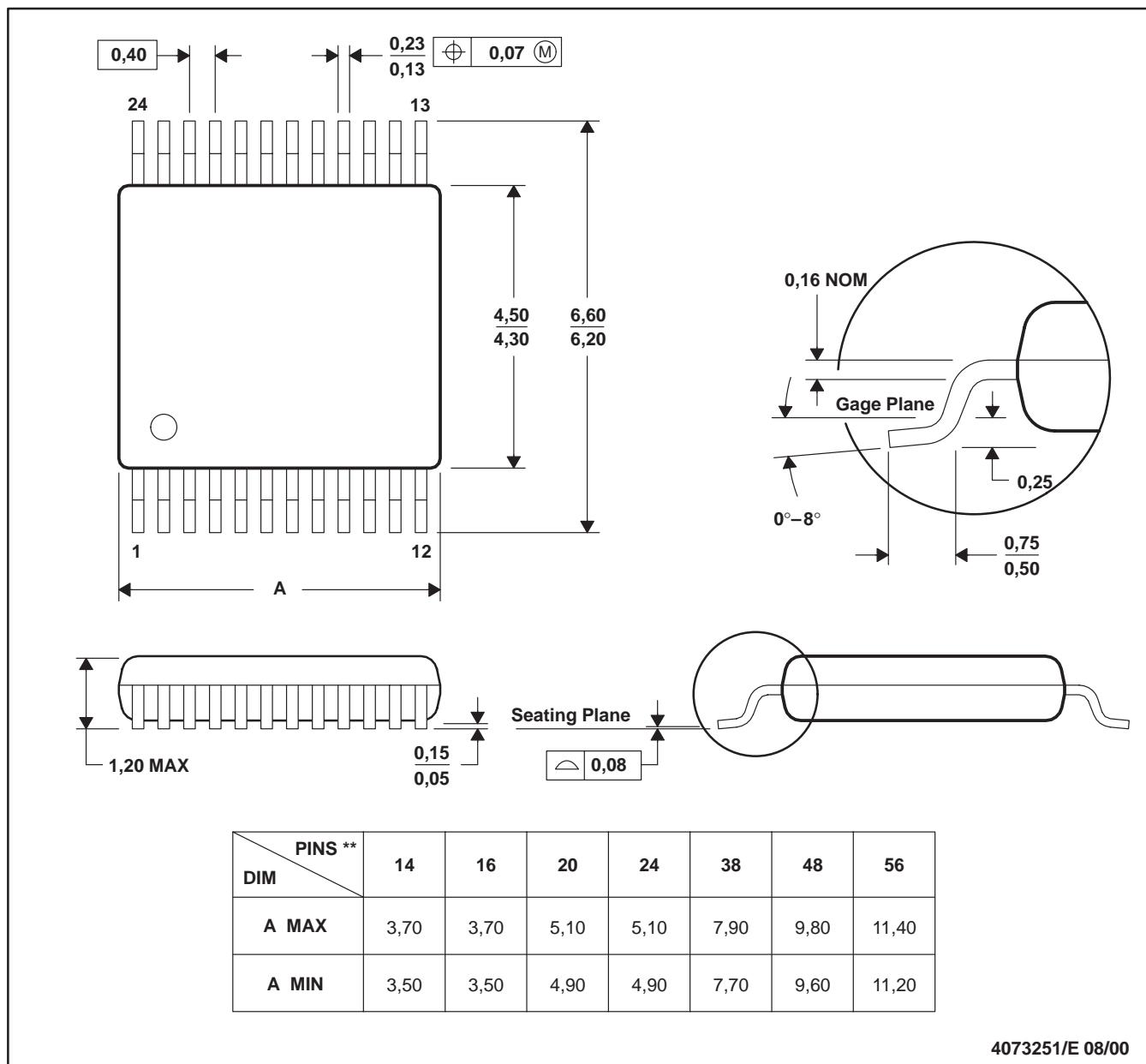
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## DGV (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

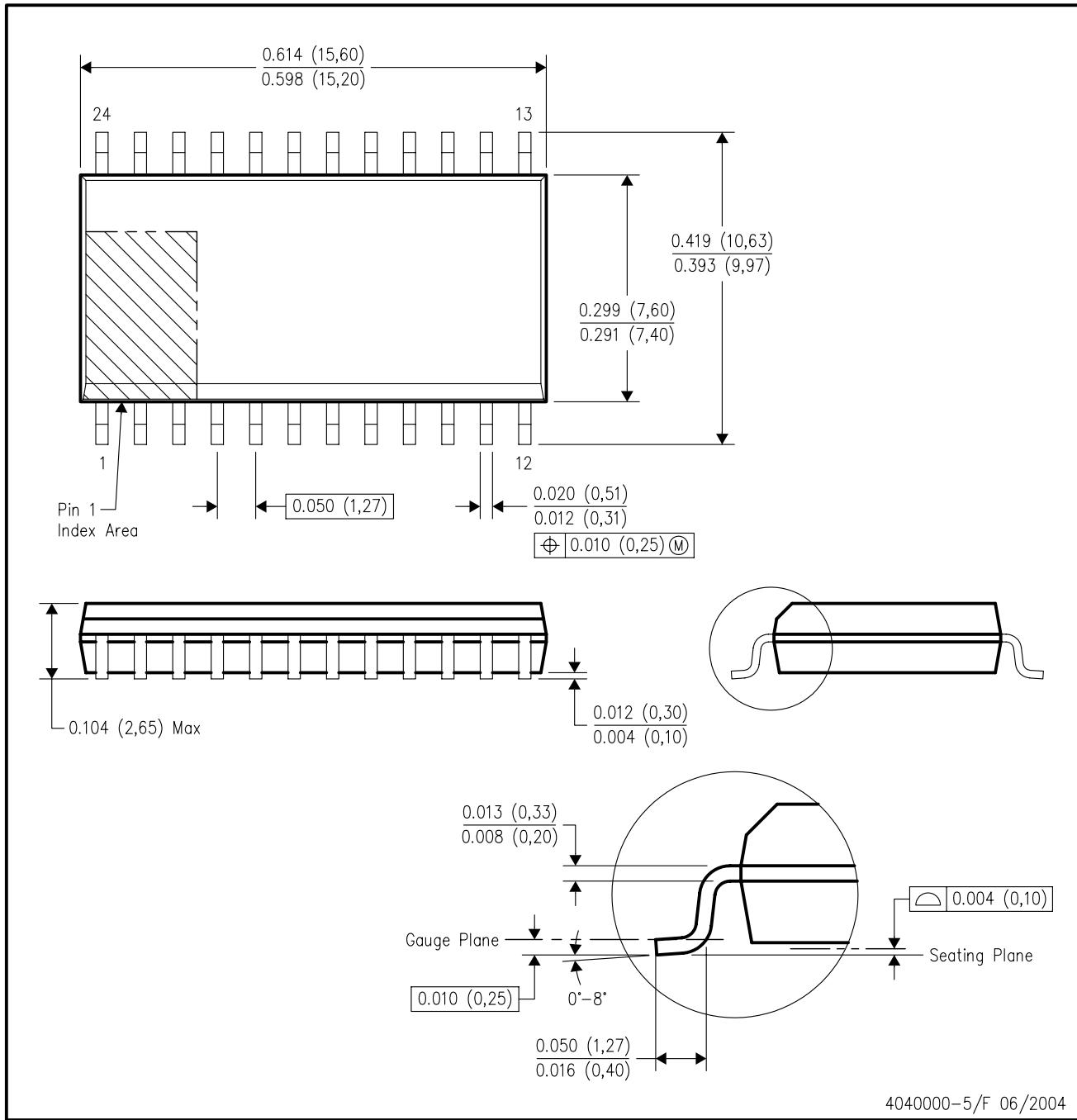
24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.  
 D. Falls within JEDEC: 24/48 Pins – MO-153  
 14/16/20/56 Pins – MO-194

## DW (R-PDSO-G24)

## PLASTIC SMALL-OUTLINE PACKAGE

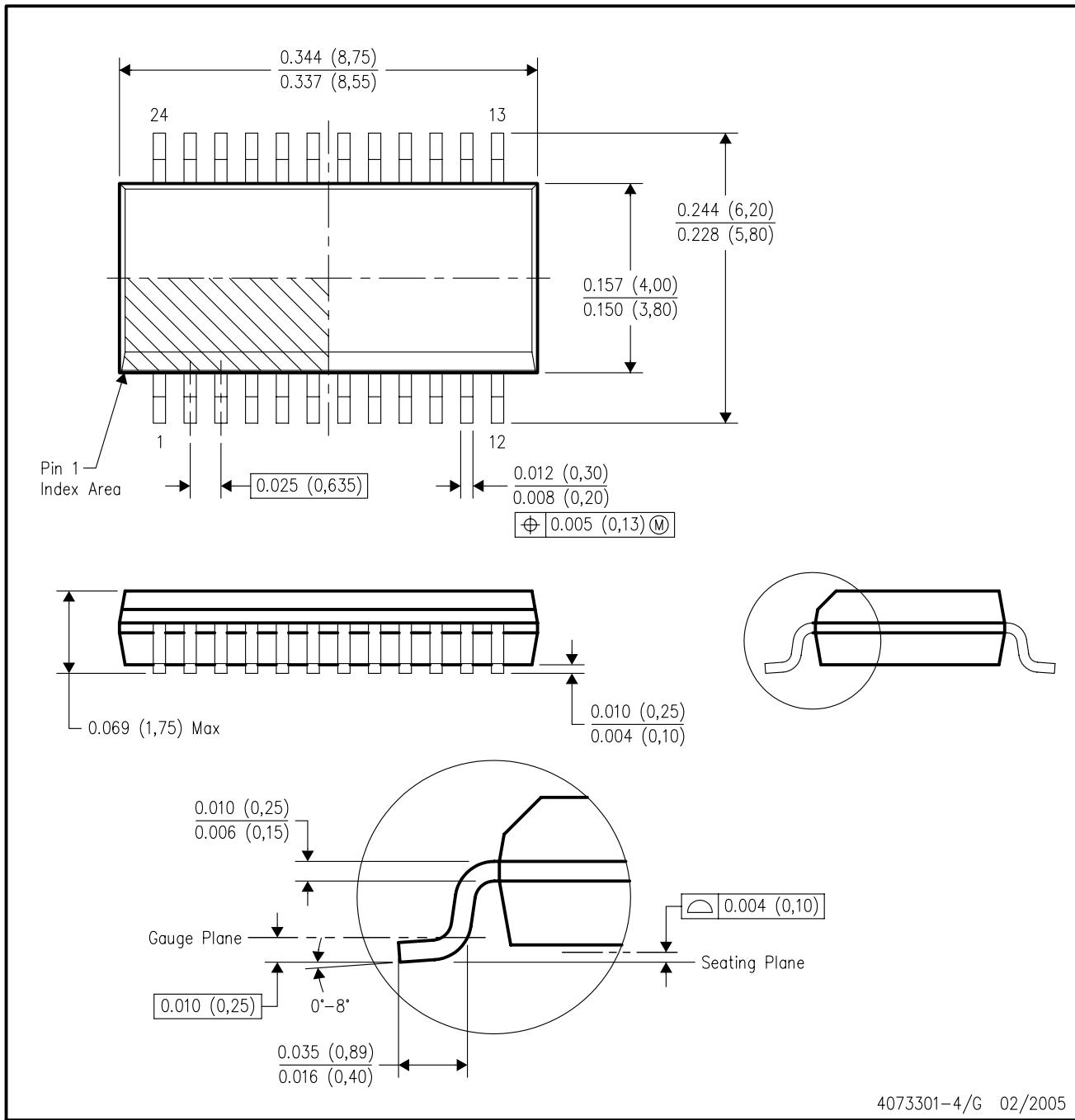


NOTES:

- All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0.15).
- Falls within JEDEC MS-013 variation AD.

## DBQ (R-PDSO-G24)

## PLASTIC SMALL-OUTLINE PACKAGE



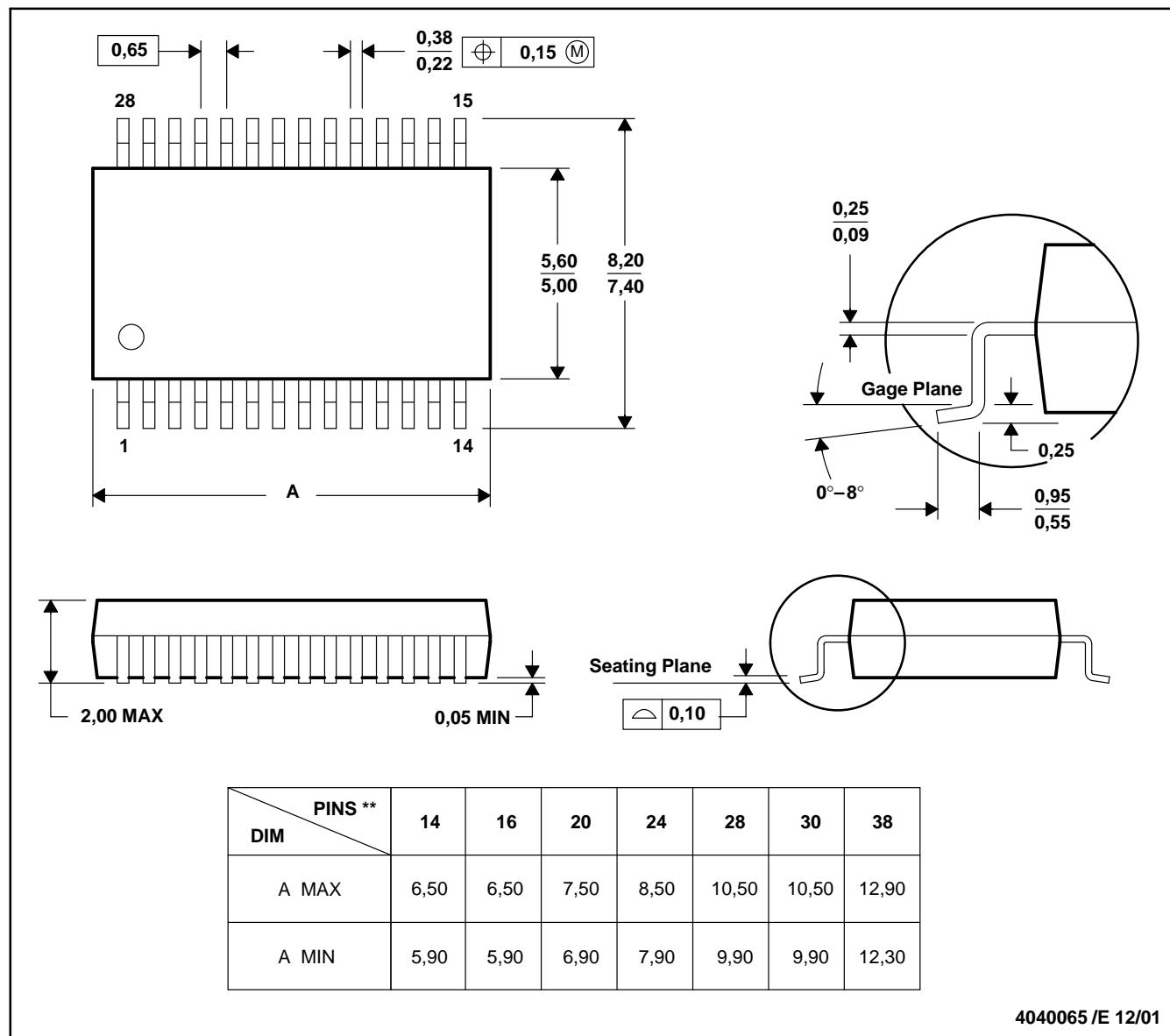
NOTES:

- All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- Falls within JEDEC MO-137 variation AE.

## DB (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

28 PINS SHOWN

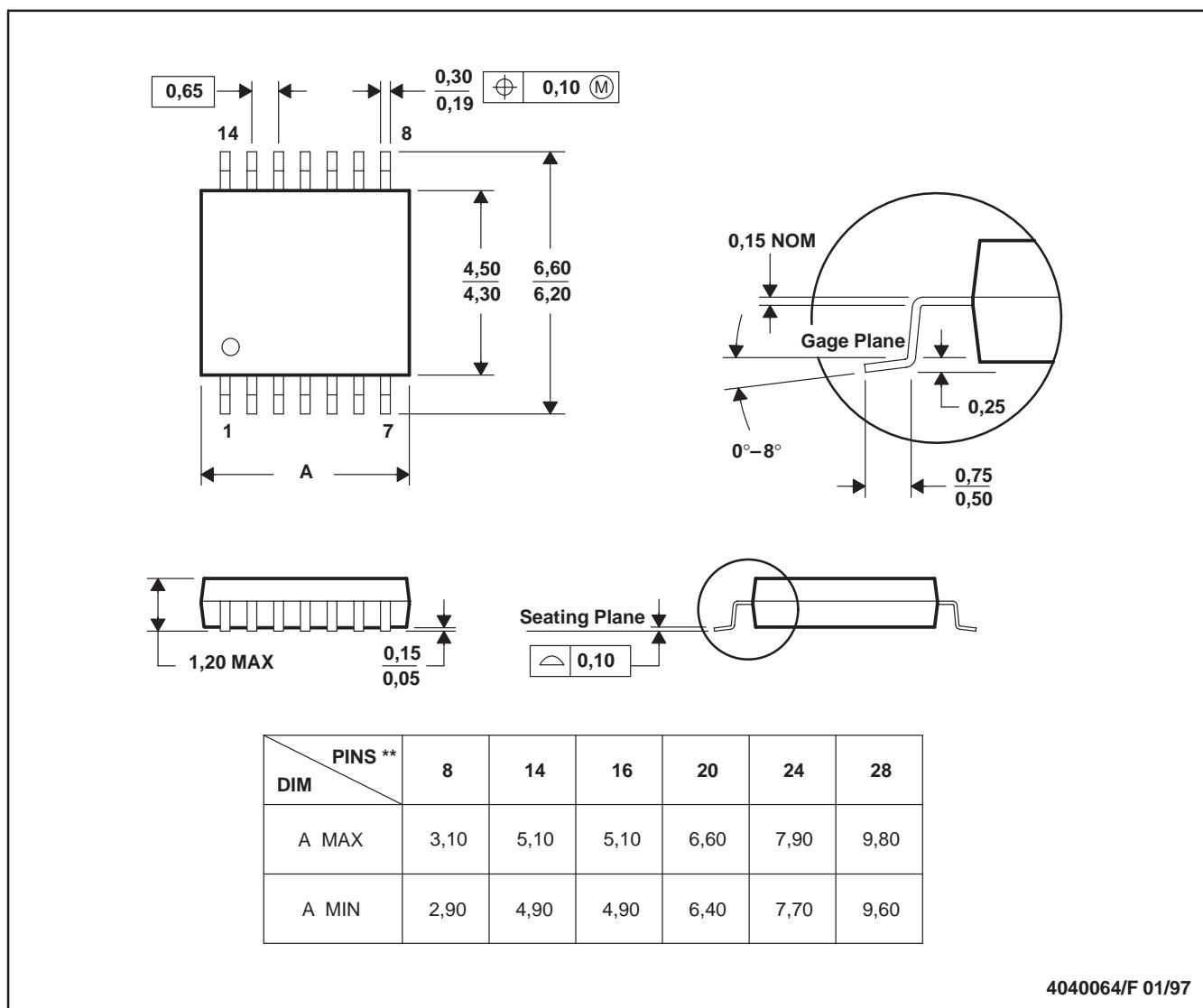


NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-150

## PW (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- Falls within JEDEC MO-153

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